

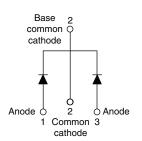
VS-30CTQ...PbF Series, VS-30CTQ...-N3 Series

Vishay Semiconductors

Schottky Rectifier, 2 x 15 A



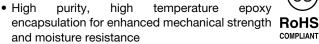
TO-220AB



PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 15 A				
V_{R}	80 V, 100 V				
V _F at I _F	0.67 V				
I _{RM} max.	7.0 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	7.50 mJ				

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation





- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	30	Α					
V _{RRM}		80/100	V					
I _{FSM}	t _p = 5 μs sine	850	Α					
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.67	V					
TJ	Range	- 55 to 175	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS- 30CTQ080PbF	VS- 30CTQ080-N3	VS- 30CTQ100PbF	VS- 30CTQ100-N3	UNITS	
Maximum DC reverse voltage	V_{R}	80	80	100	100	V	
Maximum working peak reverse voltage	V_{RWM}	80	80	100	100	V	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	per device	l=	50 % duty cycle at T _C = 129 °C, rectangular waveform		30	Α	
See fig. 5	per leg	I _{F(AV)}	30 % duty cycle at 16 = 129 0,1	15			
Maximum peak one cycle n surge current per leg	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	850	Α	
See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse			Α	
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ	
Repetitive avalanche current per leg I _{AR}		I _{AR}	Current decaying linearly to zero i Frequency limited by T _J maximun		0.50	А	



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1		15 A	T 05.00	0.86	V	
	V _{FM} ⁽¹⁾	30 A	- T _J = 25 °C	1.05		
		15 A	T 105 °C	0.67		
		30 A	T _J = 125 °C	0.82		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Dated V	0.55	m ^	
See fig. 2		T _J = 125 °C	V _R = Rated V _R	7.0	- mA	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		500	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R			

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stort temperature range	age	T _J , T _{Stg}		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		Р	DC operation	3.25		
		- R _{thJC}	DC operation	1.63	°C/W	
Typical thermal resistance case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
minimum				6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf \cdot in)	
Marking device			Coop of the TO 200AB	30CT	Q080	
			Case style TO-220AB	30CT	30CTQ100	

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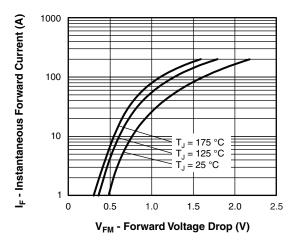


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

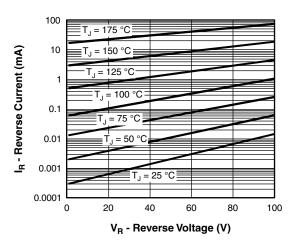


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

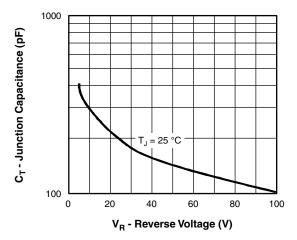


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

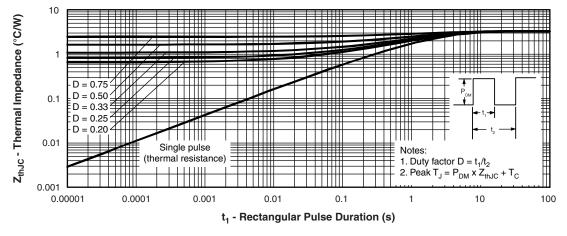


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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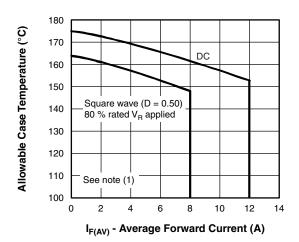


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

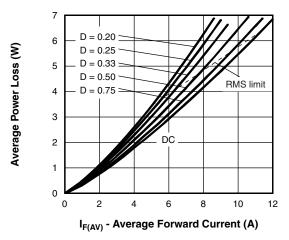


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

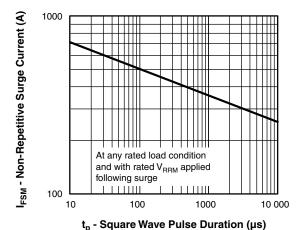


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

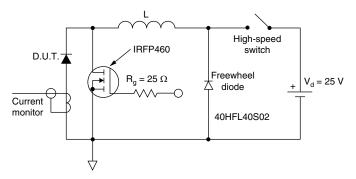


Fig. 8 - Unclamped Inductive Test Circuit

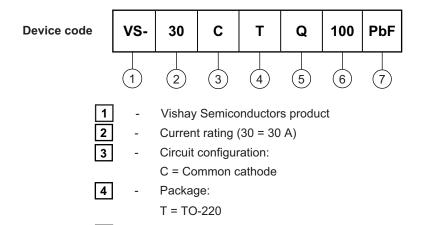
Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at (I_{F(AV)}/D) (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 10 \ V$

VS-30CTQ...PbF Series, VS-30CTQ...-N3 Series

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ORDERING INFORMATION TABLE



6 - Voltage ratings - 080 = 80 V 100 = 100 V

Schottky "Q" series

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-30CTQ080PbF	50	1000	Antistatic plastic tube					
VS-30CTQ080-N3	50	1000	Antistatic plastic tube					
VS-30CTQ100-N3	50	1000	Antistatic plastic tube					
VS-30CTQ100-N3	50	1000	Antistatic plastic tube					

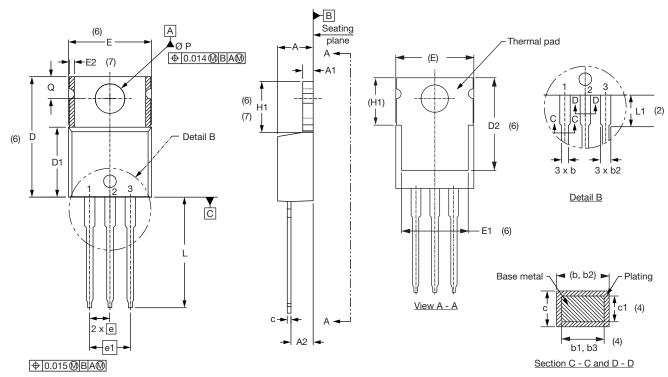
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

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